

# General-Purpose 6ch Electronic Volume with Built-in Advanced Switch

# **BD3461FS**

# **General Description**

BD3461FS is a 6ch electronic volume which has the best audio efficiency in the industry. It has an external sound mixing function (with volume) in the favorite channel for mixing of portable audio and car navigation's guide sound. Also, BD3461FS has a volume switching shock sound prevention technique called "Advanced Switch," supporting the construction of high quality car audio space by simple control.

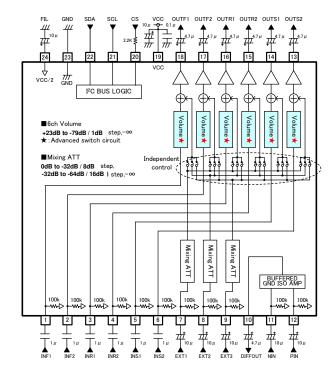
#### **Features**

- Reduce switching noise of volume by using Advanced Switch circuit.
- Mixing for external sound monaural 3ch. It is possible that is mixed to front/Rear/Sub output Lch/Rch independently.
- Built-in 3ch ATT for external sound mixing that can be controlled independently.
- Built-in buffered ground isolation amplifier inputs, ideal for external input.
- Energy-saving design resulting in low-current consumption by utilizing the Bi-CMOS process. It has the advantage in quality over scaling down the power heat control of internal regulators.
- Arranges all I/O terminals together for easier PCB layout and smaller PCB area.
- I<sup>2</sup>C BUS can be controlled by 3.3V / 5V.

# **Applications**

It is optimal for car audio. It can also be used for car navigation, audio equipment of mini Compo, micro Compo, DVD, TV, etc.

# **Typical Application Circuit**



# **Key Specifications**

Power Supply Voltage Range: 7.0V to 9.5V 25mA(Typ) Circuit Current (no signal): Total Harmonic Distortion: 0.0004% (Typ) Maximum Input Voltage: 2.35Vrms (Typ) Cross-talk between Selectors: -105dB (Typ) Volume Control Range: +23dB to -79dB Output Noise Voltage: 1.9µVrms(Typ) Residual Output Noise Voltage: 1.6μVrms (Typ) Operating Temperature Range: -40°C to +85°C

#### **Package**

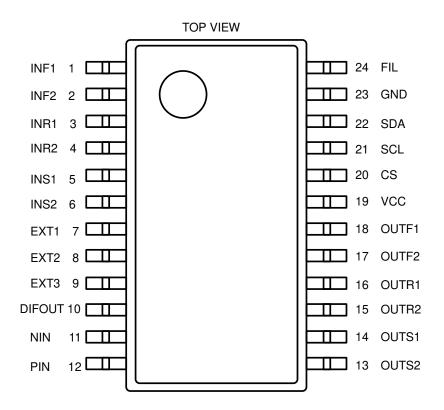
 $W(Typ) \times D(Typ) \times H(Max)$ 



Unit R : [Ω] C : [F]

OProduct structure: Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays

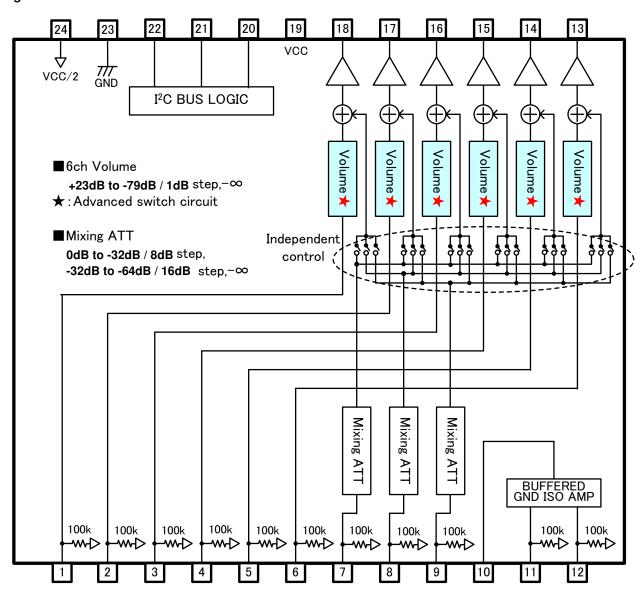
# **Pin Configuration**



# **Pin Descriptions**

Pin No.	Pin Name	Description	Pin No.	Pin Name	Description
i ili ivo.	I III INAIIIE	'	T III INO.	Till Ivallie	· ·
1	INF1	1ch Front input terminal	13	OUTS2	2ch Subwoofer output terminal
2	INF2	2ch Front input terminal	14	OUTS1	1ch Subwoofer output terminal
3	INR1	1ch Rear input terminal	15	OUTR2	2ch Rear output terminal
4	INR2	2ch Rear input terminal	16	OUTR1	1ch Rear output terminal
5	INS1	1ch Subwoofer input terminal	17	OUTF2	2ch Front output terminal
6	INS2	2ch Subwoofer input terminal	18	OUTF1	1ch Front output terminal
7	EXT1	1ch External input terminal	19	VCC	Power supply terminal
8	EXT2	2ch External input terminal	20	CS	Chip select terminal
9	EXT3	3ch External input terminal	21	SCL	I <sup>2</sup> C Communication clock terminal
10	DIFOUT	DIFF amp output terminal	22	SDA	I <sup>2</sup> C Communication data terminal
11	NIN	DIFF amp negative input terminal	23	GND	GND terminal
12	PIN	DIFF amp positive input terminal	24	FIL	VCC/2 terminal

# **Block Diagram**



**Absolute Maximum Ratings** (Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Supply Voltage	V <sub>CC</sub>	10.0V	V
Input Voltage	V <sub>IN</sub>	V <sub>CC</sub> +0.3 to GND-0.3	V
Power Dissipation	Pd	<b>1</b> (Note 1)	W
Storage Temperature	Tstg	-55 to +150	°C

<sup>(</sup>Note 1) This value decreases 8mW/°C for Ta=25°C or more.

ROHM standard board shall be mounted. Thermal resistance  $\theta$ ja = 125(°C/W). ROHM standard board Size : 70 x 70 x 1.6 (mm³)

Material: FR4 grass epoxy board (3% or less of copper foil area)

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

**Recommended Operating Conditions** 

Parameter	Symbol	Rating	Unit
Power Supply Voltage	Vcc	7.0 to 9.5	V
Temperature	Topr	-40 to +85	°C

#### **Electrical Characteristics**

(Unless specified, Ta=25°C, Vcc=8.5V, f=1kHz, V<sub>IN</sub>=1Vrms, Rg=6000, R<sub>I</sub>=10kO, INF1 input, Volume 0dB)

	ess specified, Ia=25°C, Vcc=8.5V, f=1KF	,	10, 11g 00	Limit	1132, 1141 1		,
BLOCK	Parameter	Symbol	Min	Тур	Max	Unit	Conditions
	Circuit Current (no signal)	lα	-	25	40	mA	No signal
	Voltage Gain	Gv	-1.5	0	+1.5	dB	G <sub>V</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> )
	Channel Balance	СВ	-1.5	0	+1.5	dB	CB=G <sub>V1</sub> -G <sub>V2</sub>
	Total Harmonic Distortion	THD	-	0.0004	0.05	%	V <sub>OUT</sub> =1Vrms BW=400Hz-30kHz
3AL	Output Noise Voltage *	V <sub>NO</sub>	-	1.9	10	μVrms	Rg=0Ω BW=IHF-A
GENERAL	Residual Output Noise Voltage *	V <sub>NOR</sub>	-	1.6	10	μVrms	Volume=-∞dB Rg=0Ω BW=IHF-A
	Cross-talk between Channels *	СТС	-	-105	-90	dB	Rg=0Ω CTC=20log(V <sub>OUT</sub> /V <sub>IN</sub> ) BW=IHF-A
	Ripple Rejection	RR	-	-80	-40	THD	
	Input Impedance	R <sub>IN_D</sub>	70	100	130	kΩ	
DIFF	Common Mode Rejection Ratio *	CMRR	50	65	-	dB	PIN and NIN input CMRR=20log10(V <sub>IN</sub> /V <sub>OUT</sub> ) BW=IHF-A

	$\frac{1}{1}$ Specified, $\frac{1}{1}$ $1$	12, V   \( \bullet    V	13, 11g 00	032, 11, 10	11.22, 11.11	input, voic	inc odb)
BLOCK	Parameter	Symbol		Limit		Unit	Conditions
BLC	i didilietei	Cymbol	Min	Тур	Max	Offic	Conditions
	Input Impedance	R <sub>IN_V</sub>	70	100	130	kΩ	
	Maximum Input Voltage	V <sub>IM</sub>	2	2.35	-	Vrms	V <sub>IM</sub> at THD+N(V <sub>OUT</sub> )=1% BW=400Hz-30kHz
	Maximum Gain	Gv_bst	21	23	25	dB	Gain=23dB V <sub>IN</sub> =100mVrms G <sub>V</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> )
ME	Maximum Attenuation *	Gv_min	-	-109	-90	dB	Volume=-∞dB Gv=20log(V <sub>OUT</sub> /V <sub>IN</sub> ) BW=IHF-A
VOLUME	Step Resolution	G <sub>V_STEP</sub>	-	1	-	dB	GAIN&ATT=+23dB to -79dB
	Gain Set Error	G <sub>V_ERR</sub>	-2	0	+2	dB	Gain=+1dB to +23dB
	Attenuation Set Error 1	Gv_err1	-2	0	+2	dB	ATT=-1dB to -15dB
	Attenuation Set Error 2	Gv_err2	-3	0	+3	dB	ATT=-16dB to -47dB
	Attenuation Set Error 3	Gv_err3	-4	0	+4	dB	ATT=-48dB to -79dB
	Output Impedance	Rout	-	-	50	Ω	V <sub>IN</sub> =100mVms
	Maximum Output Voltage	Vом	2	2.35	-	Vrms	THD+N=1% BW=400Hz-30kHz
-	Input Impedance	R <sub>IN_M</sub>	70	100	130	kΩ	
MIXING ATT	Maximum Attenuation *	Gм_мім	-	-90	-	dB	G <sub>M</sub> =20log(V <sub>OUT</sub> /V <sub>IN</sub> ) BW=IHF-A, ATT=-∞dB
\(\frac{1}{2}\)	Step Resolution 1	G <sub>M_STEP1</sub>	-	8	-	dB	ATT=0dB to -32dB
Σ	Step Resolution 2	G <sub>M_STEP2</sub>	-	16	-	dB	ATT=-32dB to -64dB

VP-9690A (Average value detection, effective value display) filter by Matsushita Communication is used for \* measurement. Phase between input / output is same.

# **Typical Performance Curves**

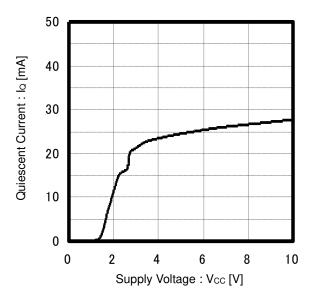


Figure 1. Quiescent Current vs Supply Voltage

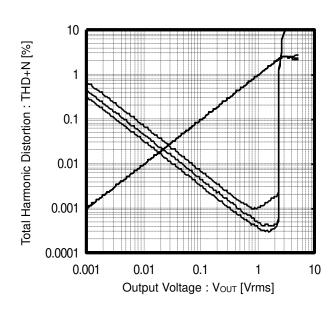


Figure 2. Total Harmonic Distortion vs Output Voltage

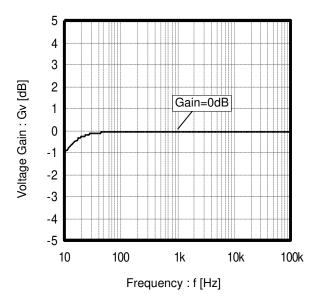


Figure 3. Voltage Gain vs Frequency

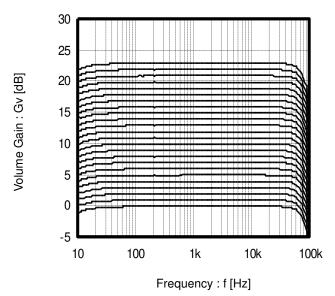


Figure 4. Volume Gain vs Frequency (0dB to +23dB)

# Typical Performance Curves - continued

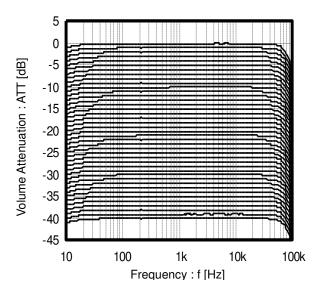


Figure 5. Volume Gain vs Frequency 1 (+0dB to -40dB)

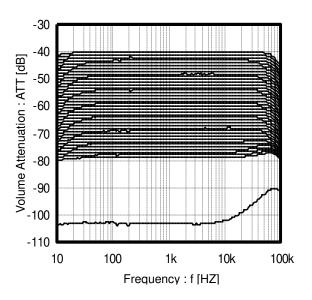


Figure 6. Volume Gain vs Frequency 2 (-41dB to -79dB)

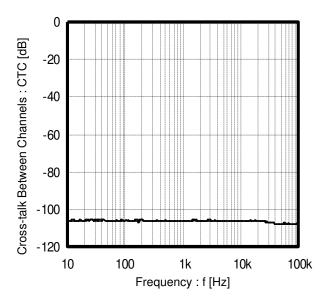


Figure 7. Cross-Talk Between Channels vs Frequency

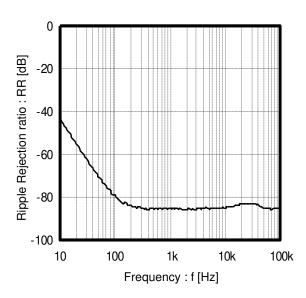


Figure 8. Ripple Rejection Ratio vs Frequency

# Typical Performance Curves - continued

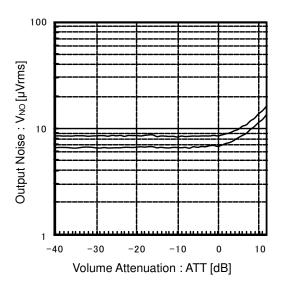


Figure 9. Output Noise vs Volume Attenuation

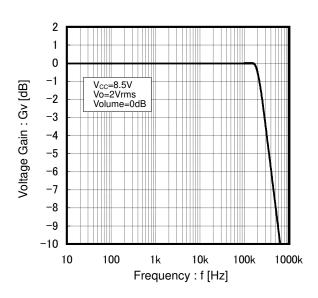


Figure 10. Volume Gain of Large Output Level vs Frequency

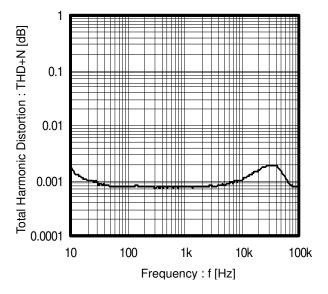


Figure 11. Total Harmonic Distortion vs Frequency

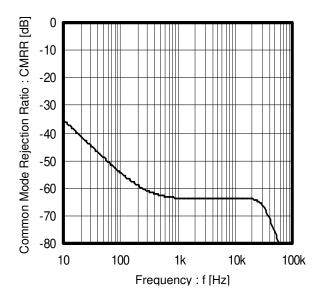


Figure 12. Common Mode Rejection Ratio vs Frequency

# **Typical Performance Curves – continued**

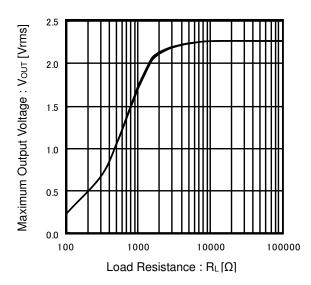


Figure 13. Maximum Output Voltage vs Load Resistance

Figure 14. Mixing Attenuation vs Frequency

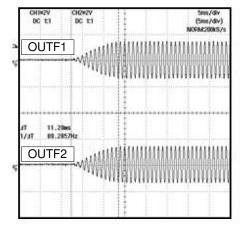


Figure 15. Advanced Switch 1

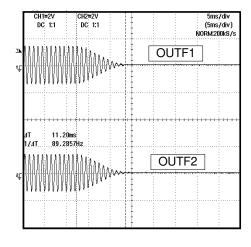


Figure 16. Advanced Switch 2

# **Timing Chart**

# **CONTROL SIGNAL SPECIFICATIONS**

# (1) Electrical Specifications and Timing for Bus Lines and I/O Stages

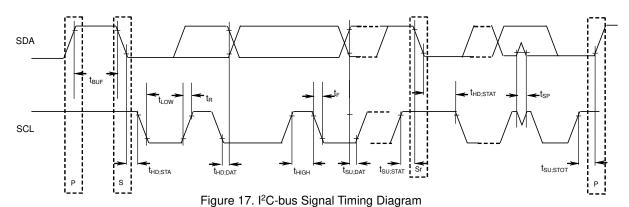


Table 1 Characteristics of the SDA and SCL bus lines for I<sup>2</sup>C-bus devices (Unless specified, Ta=25°C, Vcc=8.5V)

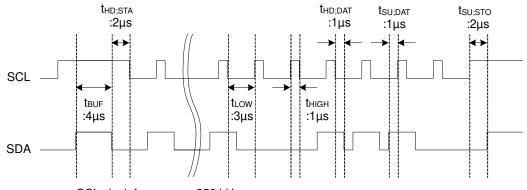
	Parameter	Symbol	Fast-mod	e I <sup>2</sup> C-bus	Unit
	rarameter	Syllibol	Min	Max	Offic
1	SCL clock frequency	fscL	0	400	kHz
2	Bus free time between a STOP and START condition	tBUF	1.3	-	μS
3	Hold time (repeated) START condition. After this period, the first clock	thd:sta	0.6		μS
3	pulse is generated	thD;STA	0.0	-	μΟ
4	LOW period of the SCL clock	tLOW	1.3	-	μS
5	HIGH period of the SCL clock	thigh	0.6	-	μS
6	Set-up time for a repeated START condition	tsu;sta	0.6	-	μS
7	Data hold time	thd;dat	0 (Note)	-	μS
8	Data set-up time	t <sub>SU;DAT</sub>	100	-	ns
9	Set-up time for STOP condition	tsu;sto	0.6	-	μS

All values referred to VIH Min and VIL Max Levels (see Table 2).

(Note) To avoid sending right after the fall-edge of SCL (VIH min of the SCL signal), the transmitter sets a holding time of 300ns or more for the SDA signal. About 7(thd:DAT), 8(tsu:DAT), make it the setup which a margin is fully in.

Table 2 Characteristics of the SDA and SCL I/O stages for I<sup>2</sup>C-bus devices

	Parameter	Cumbal	Fast-mod	le devices	Unit	
	Parameter	Symbol	Min	Max	Offic	
10	LOW level input voltage	VIL	-0.5	+1	٧	
11	HIGH level input voltage	V <sub>IH</sub>	2.3	-	٧	
12	Pulse width of spikes which must be suppressed by the input filter.	tsp	0	50	ns	
13	LOW level output voltage (open drain or open collector) at 3mA sink current	V <sub>OL1</sub>	0	0.4	<b>V</b>	
14	Input current of each I/O pin with an input voltage between 0.4V and 4.5V	l <sub>l</sub>	-10	+10	μΑ	



SCL clock frequency: 250 kHz

Figure 18. I<sup>2</sup>C Command Data Transmission Timing Diagram

# (2) I<sup>2</sup>C BUS FORMAT

		MSB LSB		MSB	LSB	MSB	LSB					
	S	Slave Address	Α	Select Addre	ss A	Data		4 P				
1	lbit	8bit	1bit	8bit	1bit	8bit	1 k	oit 1bit	_			
		S	= Sta	art condition (Rec	ognition of	start bit)						
		Slave Address	= Re	cognition of slave	address.	The first 7 bits c	orrespond to	the sla	ve address.			
			Th	e least significant	bit is "L" w	hich correspond	ds to write m	ode.				
		Α	= ACKNOWLEDGE bit (Recognition of acknowledgement)									
		Select Address	= Se	lect address corr	esponding t	to volume, bass	or treble.					
		Data	= Da	ıta on every volur	ne and tone	<b>)</b> .						
		Р	= Sto	op condition (Rec	ognition of	stop bit)						

# (3) I<sup>2</sup>C BUS Interface Protocol

(a)	Basic Forma	at							
S	Slave Add	lress	Α	Sele	ect Address	Α	Data	Α	Р
M	ISB	LSB	M	SB	LSB	MS	B LSB		

Automatic Increment (Select Address increases (+1) according to the number of data.) S Data1 Α Slave Address Select Address Data2 DataN MSB MSB MSB LSB MSB LSB LSB LSB MSB LSB

(Example) ① Data1 shall be set as data of address specified by Select Address.

- ② Data2 shall be set as data of address specified by Select Address +1.
- ③ DataN shall be set as data of address specified by Select Address +N-1.

(c) Configuration Unavailable for Transmission (In this case, only Select Address1 is set.)

S	Sla	ave Address	Α	Select Ad	ddress1	Α	D	)ata	Α	Select Ac	ddress 2	Α	Dat	ta	Α	Р	
MS	SB	LSB	M:	SB	LSB	MS	SB	LSB	Ν	/ISB	LSB	MS	SB I	LSB			
	Ī	(Note) If any	data	a is transmi	tted as Se	elec	t A	ddress	s 2 r	ext to data	, it is reco	gniz	zed				
		as	data.	not as Sel	ect Addre	ss 2	2.										

# (4) Slave Address

Because the slave address can be changed by the setting of CS, it is possible to use two chips at the same time on identical BUS.

	MSB							LSB	_
SEL Voltage Condition	A6	A5	A4	A3	A2	A1	A0	R/W	80H
GND to 0.2 x V <sub>CC</sub>	1	0	0	0	0	0	0	0	84H
0.8 x Vcc to Vcc	1	0	0	0	0	1	0	0	

Establish the CS voltage to define the setting.

# (5) Select Address & Data

	Select	MSB			Da	ata			LSB				
Items to be set	Address (hex)	D7	D6	D5	D4	D3	D2	D1	D0				
Initial Setup 1	01	0	0	0	0	0	1	0	0				
Volume 1ch Front	28		Volume Gain / Attenuation										
Volume 2ch Front	29			Vo	olume Gain	/ Attenuati	on						
Volume 1ch Rear	2A			Vo	olume Gain	/ Attenuati	on						
Volume 2ch Rear	2B			Vo	olume Gain	/ Attenuati	on						
Volume 1ch Sub	2C	2C Volume Gain / Attenuation					Volume Gain / Attenuation						
Volume 2ch Sub	2D	2D V				Volume Gain / Attenuation							
EXT 1 ON/OFF	30	EXT1	EXT1	EXT1	EXT1	EXT1	EXT1	0	0				
LXT T ON/OTT	30	S2	S1	R2	R1	F2	F1	U	0				
EXT 2 ON/OFF	31	EXT2	EXT2	EXT2	EXT2	EXT2	EXT2	0	0				
LXT Z ON/OTT	01	S2	S1	R2	R1	F2	F1	U	0				
EXT 3 ON/OFF	32	EXT3	EXT3	EXT3	EXT3	EXT3	EXT3	0	0				
LXT 3 ON/OTT	32	S2	S1	R2	R1	F2	F1	U	U				
EXT 1 ATT	33	0	0	0	0	0	EX	T1 Attenua	tion				
EXT 2 ATT	34	0	0	0	0	0	EX	T2 Attenua	tion				
EXT 3 ATT	35	0	0	0	0	0	EX	T3 Attenua	tion				
Test Mode	F0	0	0	0	0	0	0	0	0				
System Reset	FE	1	0	0	0	0	0	0	1				

Advanced Switch

(Note)

- 1. The Advanced Switch works in the latch part while changing from one function to another.
- 2. Upon continuous data transfer, the Select Address rolls over because of the automatic increment function, as shown below.

3. Changing "EXT = ON/OFF" and "EXT Atteuation", does not correspond for advance switch. Therefore, please do the measure that applies mute on the side of a set.

Select address 28, 29, 2A, 2B, 2C, 2D(hex)

Gain & ATT	MSB		Volum	e Gair	n/Atten	uation		LSB
Gaill & Al I	D7	D6	D5	D4	D3	D2	D1	D0
	0	0	0	0	0	0	0	0
(NI=+=)	0	0	0	0	0	0	0	1
Prohibition (Note)	:	•••	•	•••	•	•	:	•
	0	1	1	0	1	0	0	0
23dB	0	1	1	0	1	0	0	1
22dB	0	1	1	0	1	0	1	0
21dB	0	1	1	0	1	0	1	1
:	:	:	:	:	:	:	:	:
-78dB	1	1	0	0	1	1	1	0
-78dB	1	1	0	0	1	1	1	0
-79dB	1	1	0	0	1	1	1	1
	1	1	0	1	0	0	0	0
Prohibition (Note)	:	:	:	:	:	:	:	:
	1	1	1	1	1	1	1	0
-∞dB	1	1	1	1	1	1	1	1

Select address 30, 31, 32(hex)

MODE	MSB	SB EXT1 F1							
MODE	D7	D6	D5	D4	D3	D2	D1	D0	
OFF	EXT1	EXT1	EXT1	EXT1	EXT1	0	0	0	
ON	S2	S1	R2	R1	F2	1	U	U	

MODE	MSB	B EXT1 F2							
WIODE	D7	D6	D5	D4	D3	D2	D1	D0	
OFF	EXT1	EXT1	EXT1	EXT1	0	EXT1	0	0	
ON	S2	S1	R2	R1	1	F1	U	0	

MODE	MSB	EXT1 R1							
IVIODE	D7	D6	D5	D4	D3	D2	D1	D0	
OFF	EXT1	EXT1	EXT1	0	EXT1	EXT1	0	0	
ON	S2	S1	R2	1	F2	F1	U	U	

MODE	MSB	ISB EXT1 R2						
IVIODE	D7	D6	D5	D4	D3	D2	D1	D0
OFF	EXT1	EXT1	0	EXT1	EXT1	EXT1	0	0
ON	S2	S1	1	R1	F2	F1	U	U

MODE	MSB EXT1 S1						LSB	
IVIODE	D7	D6	D5	D4	D3	D2	D1	D0
OFF	EXT1	0	EXT1	EXT1	EXT1	EXT1	0	0
ON	S2	1	R2	R1	F2	F1	0	U

MODE	MSB	SB EXT1 S2								
WODL	D7	D6	D5	D4	D3	D2	D1	D0		
OFF	0	EXT1	EXT1	EXT1	EXT1	EXT1	0	0		
ON	1	S1	R2	R1	F2	F1	U	U		

:Initial condition

Select address 33, 34, 35(hex)

Gain	MSB		EXT Attenuation								
Gain	D7	D6	D5	D4	D3	D2	D1	D0			
0dB						0	0	0			
-8dB						0	0	1			
-16dB						0	1	0			
-24dB	0	0	0	0	0	0	1	1			
-32dB		U	U	U	U	1	0	0			
-48dB						1	0	1			
-64dB						1	1	0			
-∞dB						1	1	1			

:Initial condition

(6) About Power ON Reset Initialization inside IC is carried out at one of supply voltage circuits. Initial data is sent to all addresses at supply voltage on. Mute is ON until this initial data is sent.

Daramatar	Cumbal		Limit		Unit	Conditions
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Rise Time of VCC	trise	20	-	-	µsec	Vcc rise time from 0V to 3V
VCC Voltage of Release Power ON Reset	V <sub>POR</sub>	-	4.1	-	٧	

# **Application Information**

1. Volume Gain/Attenuation of the details

1. Volu	ıme G	aın/A	ttenu	ation	of the	e deta	IIIS										
(dB)	D7	D6	D5	D4	D3	D2	D1	D0	(dB)	D7	D6	D5	D4	D3	D2	D1	D0
+23	0	1	1	0	1	0	0	1	-29	1	0	0	1	1	1	0	1
+22	0	1	1	0	1	0	1	0	-30	1	0	0	1	1	1	1	0
+21	0	1	1	0	1	0	1	1	-31	1	0	0	1	1	1	1	1
+20	0	1	1	0	1	1	0	0	-32	1	0	1	0	0	0	0	0
+19	0	1	1	0	1	1	0	1	-33	1	0	1	0	0	0	0	1
+18	0	1	1	0	1	1	1	0	-34	1	0	1	0	0	0	1	0
+17	0	1	1	0	1	1	1	1	-35	1	0	1	0	0	0	1	1
+16	0	1	1	1	0	0	0	0	-36	1	0	1	0	0	1	0	0
+15	0	1	1	1	0	0	0	1	-37	1	0	1	0	0	1	0	1
+14	0	1	1	1	0	0	1	0	-38	1	0	1	0	0	1	1	0
+13	0	1	1	1	0	0	1	1	-39	1	0	1	0	0	1	1	1
+12	0	1	1	1	0	1	0	0	-40	1	0	1	0	1	0	0	0
+11	0	1	1	1	0	1	0	1	-41	1	0	1	0	1	0	0	1
+10	0	1	1	1	0	1	1	0	-42	1	0	1	0	1	0	1	0
+9	0	1	1	1	0	1	1	1	-43	1	0	1	0	1	0	1	1
+8	0	1	1	1	1	0	0	0	-44	1	0	1	0	1	1	0	0
+7	0	1	1	1	1	0	0	1	-45	1	0	1	0	1	1	0	1
+6	0	1	1	1	1	0	1	0	-46	1	0	1	0	1	1	1	0
+5	0	1	1	1	1	0	1	1	-47	1	0	1	0	1	1	1	1
+4	0	1	1	1	1	1	0	0	-48	1	0	1	1	0	0	0	0
+3	0	1	1	1	1	1	0	1	-49	1	0	1	1	0	0	0	1
+2	0	1	1	1	1	1	1	0	-50	1	0	1	1	0	0	1	0
+1	0	1	1	1	1	1	1	1	-51	1	0	1	1	0	0	1	1
0	1	0	0	0	0	0	0	0	-52	1	0	1	1	0	1	0	0
-1	1	0	0	0	0	0	0	1	-53	1	0	1	1	0	1	0	1
-2	1	0	0	0	0	0	1	0	-54	1	0	1	1	0	1	1	0
-3	1	0	0	0	0	0	1	1	-55	1	0	1	1	0	1	1	1
-4	1	0	0	0	0	1	0	0	-56	1	0	1	1	1	0	0	0
-5	1	0	0	0	0	1	0	1	-57	1	0	1	1	1	0	0	1
-6	1	0	0	0	0	1	1	0	-58	1	0	1	1	1	0	1	0
-7	1	0	0	0	0	1	1	1	-59	1	0	1	1	1	0	1	1
-8	1	0	0	0	1	0	0	0	-60	1	0	1	1	1	1	0	0
-9	1	0	0	0	1	0	0	1	-61	1	0	1	1	1	1	0	1
-10	1	0	0	0	1	0	1	0	-62	1	0	1	1	1	1	1	0
-11	1	0	0	0	1	0	1	1	-63	1	0	1	1	1	1	1	1
-12	1	0	0	0	1	1	0	0	-64	1	1	0	0	0	0	0	0
-13	1	0	0	0	1	1	0	1	-65	1	1	0	0	0	0	0	1
-14	1	0	0	0	1	1	1	0	-66	1	1	0	0	0	0	1	0
-15	1	0	0	0	1	1	1	1	-67	1	1	0	0	0	0	1	1
-16	1	0	0	1	0	0	0	0	-68	1	1	0	0	0	1	0	0
-17	1	0	0	1	0	0	0	1	-69	1	1	0	0	0	1	0	1
-18	1	0	0	1	0	0	1	0	-70	1	1	0	0	0	1	1	0
-19	1	0	0	1	0	0	1	1	-71	1	1	0	0	0	1	1	1
-20	1	0	0	1	0	1	0	0	-72	1	1	0	0	1	0	0	0
-21	1	0	0	1	0	1	0	1	-73	1	1	0	0	1	0	0	1
-22	1	0	0	1	0	1	1	0	-74	1	1	0	0	1	0	1	0
-23	1	0	0	1	0	1	1	1	-75	1	1	0	0	1	0	1	1
-24	1	0	0	1	1	0	0	0	-76	1	1	0	0	1	1	0	0
-25	1	0	0	1	1	0	0	1	-77	1	1	0	0	1	1	0	1
-26	1	0	0	1	1	0	1	0	-78	1	1	0	0	1	1	1	0
-27	1	0	0	1	1	0	1	1	-79	1	1	0	0	1	1	1	1
-28	1	0	0	1	1	1	0	0	-∞	1	1	1	1	1	1	1	1

: Initial condition

# 2. Application Circuit Diagram

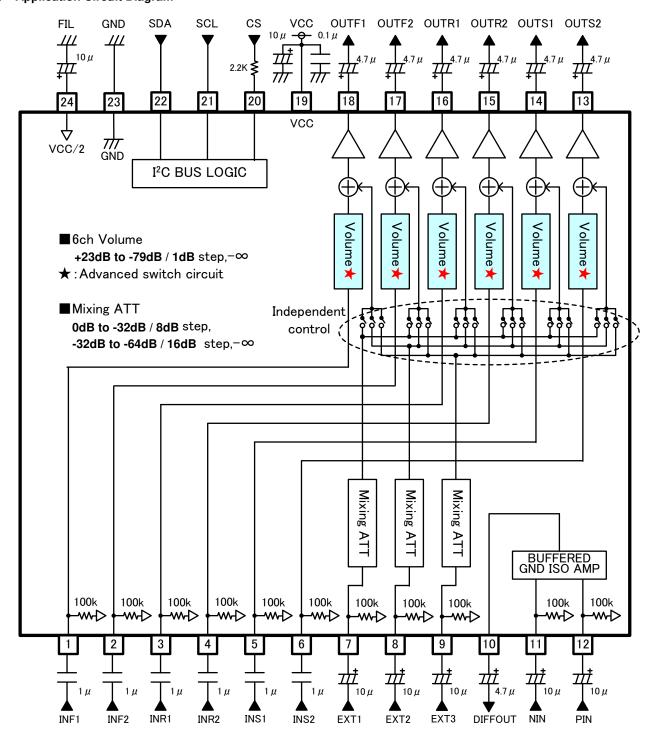


Figure 19. Application Circuit Diagram

Unit R : [Ω] C : [F]

# Notes on wiring

- ①Please connect the decoupling capacitor of a power supply in the shortest distance as much as possible to GND.
- ②Lines of GND shall be one-point connected.
- ③Wiring pattern of Digital shall be away from that of analog unit and cross-talk shall not be acceptable.
- (4) Lines of SCL and SDA of I<sup>2</sup>C BUS shall not be parallel if possible.
  - The lines shall be shielded, if they are adjacent to each other.
- ⑤Lines of analog input shall not be parallel if possible. The lines shall be shielded, if they are adjacent to each other.

# **Power Dissipation**

About the thermal design by the IC

Characteristics of an IC have a great deal to do with the temperature at which it is used, and exceeding absolute maximum ratings may degrade and destroy elements. Careful consideration must be given to the heat of the IC from the two standpoints of immediate damage and long-term reliability of operation.

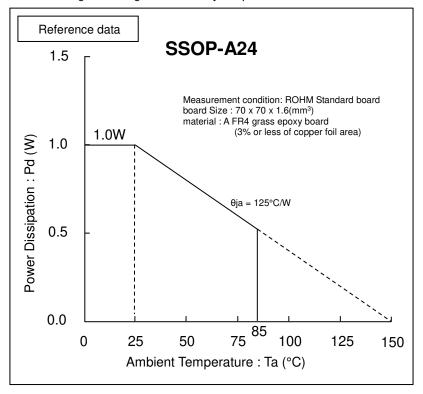


Figure 20. Temperature Derating Curve (SSOP-A24)

(Note) Values are actual measurements and are not guaranteed. Power dissipation values vary according to the board on which the IC is mounted.

I/O Equivalent Circuits

<b>Equivalent</b>	Circuits		
Terminal No.	Terminal Voltage	Equivalent Circuit	Terminal Description
INF1 INF2 INR1 INR2 INS1 INS2 NIN PIN EXT1 EXT2 EXT3	4.25	VCC	Signal input terminal. The input impedance is $100 k\Omega$ (typ).
DIFOUT OUTS2 OUTS1 OUTR2 OUTR1 OUTF2 OUTF1	4.25	VCC GND	Fader output terminal.
cs	-	VCC GND	Slave address selection terminal. "CS" is "High" to slave address "84 H" "CS" is "Low" to slave address "80 H"

The values in the input/output equivalent circuits are reference values only and are not guaranteed.

I/O Equivalent Circuits - continued

Equivalent (	Circuits – co	ontinuea	
Terminal Name	Terminal Voltage	Equivalent Circuit	Terminal Description
VCC	8.5		Power supply terminal.
SCL	-	VCC O 1.65V	A terminal for clock input of I <sup>2</sup> C BUS communication.
SDA	-	VCC O GND I.65V	A terminal for data input of I <sup>2</sup> C BUS communication.
GND	0		Ground terminal.
FIL	4.25	VCC	Voltage for reference bias of analog signal system. The simple precharge circuit and simple discharge circuit for an external capacitor are built in.

The values in the input/output equivalent circuits are reference values only and are not guaranteed.

# **Operational Notes**

# 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

# 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

#### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

#### 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

#### 7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

#### 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

#### 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

# 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

#### 11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

# 12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

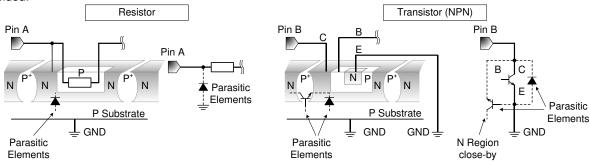
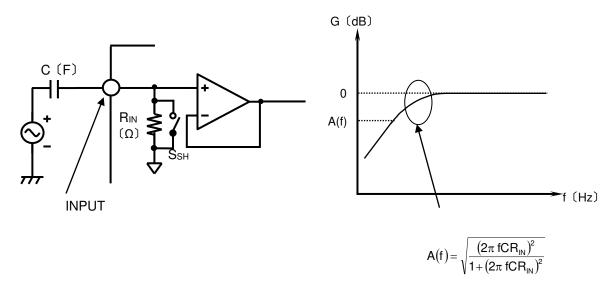


Figure 21. Example of monolithic IC structure

# 13. About a Signal Input Part

# **About Input Coupling Capacitor Constant Value**

The constant value of input coupling capacitor C(F) is decided with respect to the input impedance  $R_{IN}(\Omega)$  at the input signal terminal of the IC. The first HPF characteristic of RC is composed.

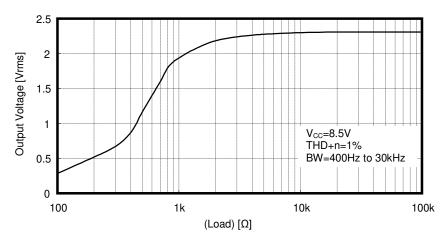


# 14. About Output Load Characteristics

The usages of output load are below (reference). Please use more than  $10[k\Omega](TYP)$  load.

Output pin on target

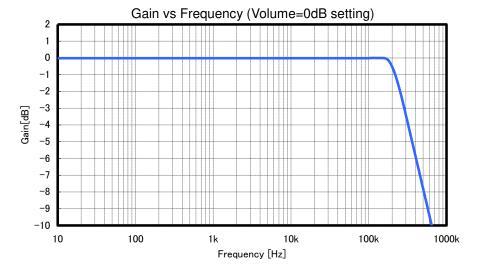
Pin Name	Pin Name	Pin Name	Pin Name
OUTF1	OUTR1	OUTS1	DIFOUT
OUTF2	OUTR2	OUTS2	



Output Load Characteristic at Vcc=8.5V. (Reference)

# 15. Frequency Characteristic at Large Output Level

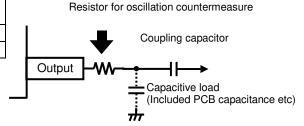
High slew-rate amplifiers are used for high quality sound. This IC corresponds to "192kHz sampling on DVD-Audio" which is highest quality. Output level is "2Vrms, 192kHz flat(typ)". (See the below graph (reference)).



# 16. Oscillation Countermeasure for GND Isolation Amplifier Outputs

Using higher capacitor than 10pF at GND isolation amplifier outputs (DIFOUT) may cause oscillation. As oscillation countermeasure, insert resistor in series to terminal directly as below.

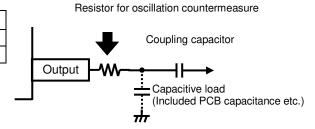
Capacitance	Resistor in series to terminal directly	
C < 10pF	Not necessary	
10 < C < 100pF	220Ω	



# 17. Oscillation Countermeasure for Volume Outputs at Power Supply ON/OFF

If using higher capacitor than 22pF at volume outputs, oscillation may occur for a moment when turning ON/OFF power supply (when Vcc is about 3V to 4V). As oscillation countermeasure, insert resistor in series to terminal directly as shown below, and set volume output to mute outside this device when turning ON/OFF power supply.

Capacitance	Resistor in series to terminal directly	
C < 22pF	Not necessary	
22 < C < 220pF	220Ω	



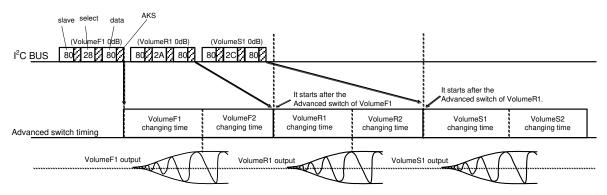
# 18. I<sup>2</sup>C BUS Transferring Data

# [1] Types of Data Transfer

- 1.1 The data transfer without Advanced Switch (data transfer without data latching format) does not have regulations on transferring data.
- 1.2 The data transfer with Advanced Switch (data transfer with data latching format) does not have regulations on transferring data too. But Advanced Switch data transfer follows the order in [2].

#### [2] Advanced Switch Data Transfer

- 2-1. The timing chart of Advanced Switch data transfer is as follows.
- Data Transfer Example 1



It is the same even if it transfers data in auto increment mode.

There are no timing regulations in I<sup>2</sup>C BUS transferring data. But the changing time starts after the end of the present change. In addition, the timing of Advanced Switch is not dependent on transferring data turn. Instead, it follows the following turn.

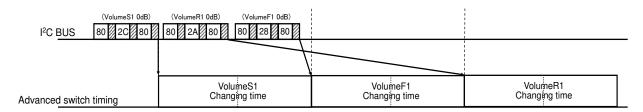
Group(1) Group(2) Group(3) VolumeF1 VolumeR1 VolumeS1 28h 2Ah 2Ch VolumeR2 VolumeS2 VolumeF2 29h 2Dh 2Bh Select address

# Advanced Switch Start Turn

(Note) The block in the same group can start the Advanced Switch at the same time.

# ■ Data Transfer Example 2

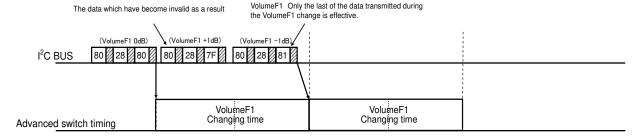
The data transfer turn differs from the actual change turn as shown below.



Please transfer data after the present Advanced Switch, if it wants to make a transferring data turn and Advanced Switch turn the same.

# ■ Data Transfer Example 3

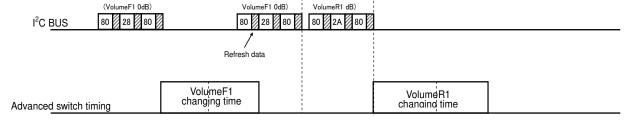
Priority is given to the data of the same select address when it is transferred to the timing which Advanced Switch has not ended. In addition, when two or more data are transferred to the same select address, the end transferred data is effective.



#### ■Data Transfer Example 4

Refresh data is the same as the present setup data, therefore Advanced Switch does not change.

The gain change data of other channels are transferred after refresh data as shown below.



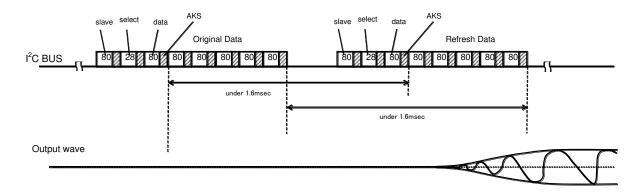
[3] Attention of Transferring Data

BD3461FS cannot set the data transfer from a microcomputer correctly on very rare occasions. In such cases, the following phenomenon may occur.

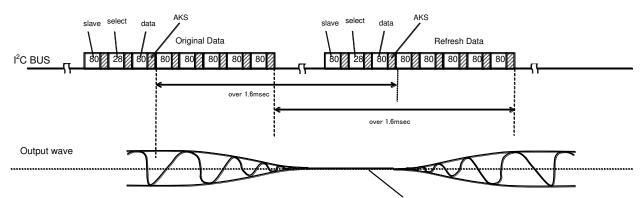
- 1. Volume gain does not change.
- 2. Volume gain changes to MUTE.

Therefore, the data transfer from a microcomputer should send data as shown in the following conditions.

① When the Volume change data send, please send the same data twice as below.

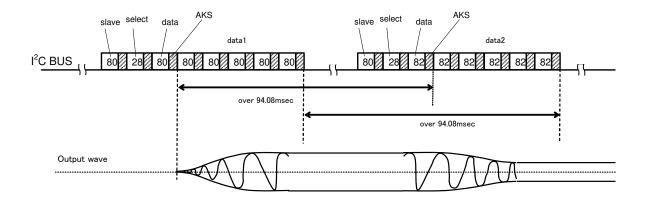


If Refresh data can't be sent like ①timing, the output wave may be mute momentarily.

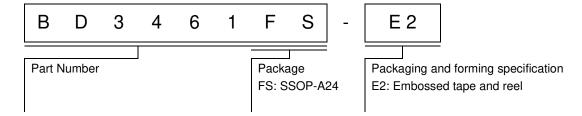


Output wave may not change the gain or may be mute until refresh data reception.

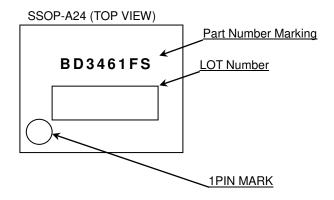
② If Volume change data can send over 94.08msec interval transferring data, there is no need to send Refresh data.



# **Ordering Information**



# **Marking Diagram**



Physical Dimension, Tape and Reel Information Package Name SSOP-A24 Max10.35 (include.BURR)  $8 \pm 0$ .  $4\pm0$ .  $2\pm 0$ . H 0  $0.\ \ 1\ 7\ ^{+0.\ 1}_{-0.\ 0\ 5}$  $8 \pm 0$ . (UNIT: mm)  $0.1\pm 0.$ PKG:SSOP-A24 Drawing No. : EX133-5001-1 0.  $38 \pm 0.1$ 0.8 □ 0. 1 <Tape and Reel information> Embossed carrier tape Tape 2000pcs Quantity **E2** Direction The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand of feed Direction of feed 1pin Reel \*Order quantity needs to be multiple of the minimum quantity.

# **Revision History**

Date	Revision	Changes	
16.Dec.2015	001	New Release	

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Ī	JÁPAN	USA	EU	CHINA
Ī	CLASSⅢ	CLASSIII	CLASS II b	CL ACCIII
	CLASSIV		CLASSⅢ	CLASSⅢ

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  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
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  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
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  - [h] Use of the Products in places subject to dew condensation
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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
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- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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